



# **TCM680**

# +5V TO $\pm$ 10V VOLTAGE CONVERTER

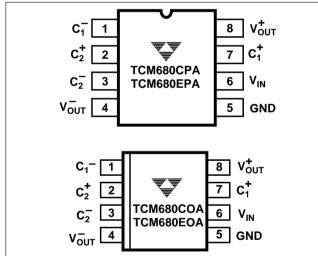
# FEATURES

- 99% Voltage Conversion Efficiency
- **85% Power Conversion Efficiency**
- Wide Voltage Range .....+2.0V to +5.5V
- Only 4 External Capacitors Required
- Space Saving 8-Pin SOIC Design

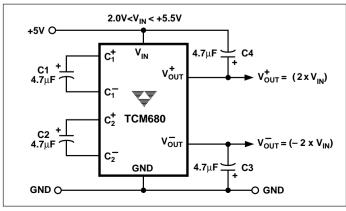
#### APPLICATIONS

- ±10V From +5V Logic Supply
- ±6V From a 3V Lithium Cell
- Handheld Instruments
- Portable Cellular Phones
- LCD Display Bias Generator
- Panel Meters
- Operational Amplifier Power Supplies

#### PIN CONFIGURATIONS (DIP AND SOIC)



#### **TYPICAL OPERATING CIRCUIT**



## **GENERAL DESCRIPTION**

The TCM680 is a dual charge pump voltage converter that develops output voltages of +2V<sub>IN</sub> and – 2V<sub>IN</sub> from a single input voltage of +2.0V to +5.5V. Common applications include  $\pm 10V$  from a single +5V logic supply, and  $\pm 6V$  from a +3V lithium battery.

The TCM680 is packaged in a space-saving 8-pin SOIC package and requires only four inexpensive external capacitors. The charge pumps are clocked by an on-board 8kHz oscillator. Low output source impedances (typically  $150\Omega$ ) provides maximum output currents of 10mA for each output. Typical power conversion efficiency is 85%.

High efficiency, small installed size and low cost make the TCM680 suitable for a wide variety of applications that need both positive and negative power supplies derived from a single input voltage.

# **ORDERING INFORMATION**

Part No.	Package	Temperature
TCM680COA	8-Pin SOIC	0°C to +70°C
TCM680CPA	8-Pin Plastic DIP	0°C to +70°C
TCM680EOA	8-Pin SOIC	- 40°C to +85°C
TCM680EPA	8-Pin Plastic DIP	- 40°C to +85°C
TC7660EV	Charge Pump Family Evaluation Kit	

# **TCM680**

#### **ABSOLUTE MAXIMUM RATINGS\***

V <sub>IN</sub>	+6.0V
V <sub>0</sub> UT	+12.0V
Vout	– 12.0V
Vout Short-Circuit Duration	Continuous
V <sub>OUT</sub> Current	75mA
V <sub>IN</sub> dV/dT	1V/µsec

Power Dissipation ( $T_A \le 70^{\circ}C$ )	
Plastic DIP	730mW
Small Outline	470mW
Storage Temperature	– 65°C to +150°C
Lead Temperature (Soldering, 10 sec)	)+300°C

\*Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or other conditions above those indicated in the operation section of the specification is not implied. Exposure to the Absolute Maximum Ratings conditions for extended periods of time may affect device reliability.

## **ELECTRICAL CHARACTERISTICS:** $V_{IN} = +5V$ , $T_A = +25^{\circ}C$ , test circuit Figure 1, unless otherwise indicated.

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
	Supply Voltage Range	$MIN. \leq T_A \leq MAX.,  R_L = 2k\Omega$	2.0	1.5 to 5.5	5.5	V
	Supply Current	$V_{IN} = 3V, R_L = \infty$		0.5	1	mA
		$V_{IN} = 5V, R_L = \infty$	_	1	2	
		$V_{IN}$ = 5V, 0°C $\leq$ T <sub>A</sub> $\leq$ +70°C, R <sub>L</sub> = $\infty$	—		2.5	
		$V_{IN}$ = 5V, - 40°C $\leq$ T <sub>A</sub> $\leq$ +85°C, R <sub>L</sub> = $\infty$	—	—	3	
	Negative Charge Pump Output	$I_{L}^{-} = 10 \text{mA}, I_{L}^{+} = 0 \text{mA}, V_{IN} = 5 \text{V}$		140	180	Ω
	Source Resistance	$I_{L}^{-}=$ 5mA, $I_{L}^{+}=$ 0mA, $V_{IN}=$ 2.8V	_	180	250	
		$I_{L}^{-}= 10 \text{mA}, I_{L}^{+}= 0 \text{mA}, V_{IN} = 5 \text{V}$ :				
		$0^{\circ}C \leq T_{A} \leq +70^{\circ}C$	_		220	
		$-40^{\circ}C \le T_A \le +85^{\circ}C$	_	—	250	
	Positive Charge Pump Output	$I_{L}^{+} = 10 \text{mA}, I_{L}^{-} = 0 \text{mA}, V_{IN} = 5 \text{V}$		140	180	Ω
	Source Resistance	$I_{L}^{+} = 5mA, I_{L}^{-} = 0mA, V_{IN} = 2.8V$	_	180	250	
		$I_{L}^{+} = 10 \text{mA}, I_{L}^{-} = 0 \text{mA}, V_{IN} = 5 \text{V}$ :				
		$0^{\circ}C \leq T_{A} \leq +70^{\circ}C$	_		220	
		$-40^{\circ}C \le T_A \le +85^{\circ}C$	—	_	250	
Fosc	Oscillator Frequency		-	21	_	kHz
P <sub>EFF</sub>	Power Efficiency	$R_L = 2k\Omega$	_	85	—	%
V <sub>OUT</sub> E <sub>FF</sub>	Voltage Conversion Efficiency	$V_{OUT}^{+}, R_{L} = \infty$	97	99		%
		$V_{OUT}$ , $R_L = \infty$	97	99		

TelCom Semiconductor reserves the right to make changes in the circuitry or specifications detailed in this manual at any time without notice. Minimums and maximums are guaranteed. All other specifications are intended as guidelines only. TelCom Semiconductor assumes no responsibility for the use of any circuits described herein and makes no representations that they are free from patent infringement.

# **PIN DESCRIPTION**

Symbol	Description
C <sub>1</sub>	Input. Capacitor C1 negative terminal.
C <sub>2</sub> <sup>+</sup>	Input. Capacitor C2 positive terminal.
$C_{\overline{2}}$	Input. Capacitor C2 negative terminal.
Vout	Output. Negative output voltage (-2VIN).
GND	Input. Device ground.
V <sub>IN</sub>	Input. Power supply voltage.
C <sub>1</sub> <sup>+</sup>	Input. Capacitor C1 positive terminal.
Vout	Output. Positive output voltage (+2VIN)
	C <sub>1</sub> C <sub>2</sub> C <sub>2</sub> V <sub>0UT</sub> GND V <sub>IN</sub>

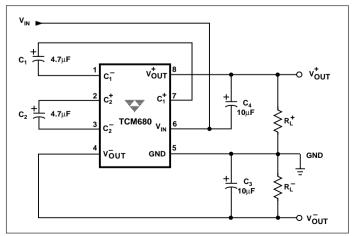


Figure 1. Test Circuit

# +5V TO $\pm$ 10V VOLTAGE CONVERTER

#### DETAILED DESCRIPTION

#### Phase 1

 $V_{SS}$  charge storage – The positive side of capacitors  $C_1$ and  $C_2$  are connected to +5V at the start of this phase.  $C_1^+$  is then switched to ground and the charge in  $C_1^-$  is transferred to  $C_2^-$ . Since  $C_2^+$  is connected to +5V, the voltage potential across capacitor  $C_2$  is now 10V.

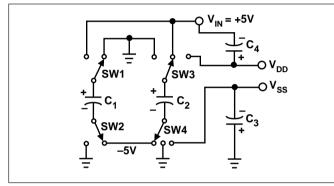


Figure 2. Charge Pump – Phase 1

#### Phase 2

 $V_{SS}$  transfer – Phase two of the clock connects the negative terminal of  $C_2$  to the  $V_{SS}$  storage capacitor  $C_3$  and the positive terminal of  $C_2$  to ground, transferring the generated –10V to  $C_3$ . Simultaneously, the positive side of capacitor  $C_1$  is switched to +5V and the negative side is connected to ground.

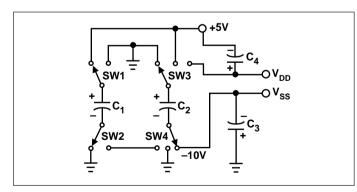
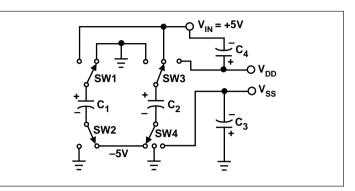


Figure 3. Charge Pump – Phase 2

#### Phase 3

 $V_{DD}$  charge storage – The third phase of the clock is identical to the first phase – the charge transferred in C<sub>1</sub> produces –5V in the negative terminal of C<sub>1</sub>, which is applied to the negative side of capacitor C<sub>2</sub>. Since C<sub>2</sub><sup>+</sup> is at +5V, the voltage potential across C<sub>2</sub> is 10V.





#### Phase 4

 $V_{DD}$  transfer – The fourth phase of the clock connects the negative terminal of  $C_2$  to ground, and transfers the generated 10V across  $C_2$  to  $C_4$ , the  $V_{DD}$  storage capacitor. Again, simultaneously with this, the positive side of capacitor  $C_1$  is switched to +5V and the negative side is connected to ground, and the cycle begins again.

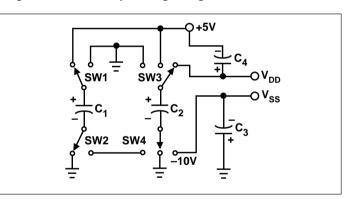


Figure 5. Charge Pump – Phase 4

#### MAXIMUM OPERATING LIMITS

The TCM680 has on-chip zener diodes that clamp  $V_{IN}$  to 5.8V,  $V_{OUT}^{+}$  to 11.6V, and  $V_{OUT}^{-}$  to -11.6V. Never exceed the maximum supply voltage or excessive current will be shunted by these diodes, potentially damaging the chip. The TCM680 will operate over the entire operating temperature range with an input voltage of 2V to 5.5V.

# **TCM680**

## **EFFICIENCY CONSIDERATIONS**

Theoretically a charge pump can approach 100% efficiency under the following conditions:

- The charge Pump switches have virtually no offset and extremely low on resistance
- Minimal power is consumed by the drive circuitry
- The impedances of the reservoir and pump capacitors are negligible

For the TCM680, efficiency is as shown below:

Power Loss =  $(V_{DROP}^{+})(I_{OUT}^{+}) + (V_{DROP}^{-})(I_{OUT}^{-})$ 

There will be a substantial voltage difference between  $(V_{OUT}^{+} - V_{IN})$  and  $V_{IN}$  for the positive pump and between  $V_{OUT}^{+}$  and  $V_{\Theta UT}$  if the impedances of the pump capacitors  $C_1$  and  $C_2$  are high with respect to the output loads.

Larger values of reservoir capacitors  $C_3$  and  $C_4$  will reduce output ripple. Larger values of both pump and reservoir capacitors improve the efficiency. See "Capacitor Selection" in Applications Section.

# **APPLICATIONS**

#### **Positive and negative Converter**

The most common application of the TCM680 is as a dual charge pump voltage converter which provides positive and negative outputs of two times a positive input voltage. The simple circuit of Figure 6 performs this same function using the TCM680 and external capacitors,  $C_1$ ,  $C_2$ ,  $C_3$  and  $C_4$ .

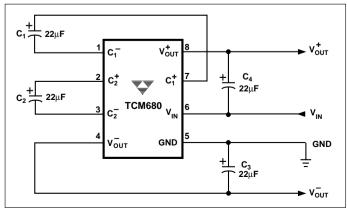


Figure 6. Positive and Negative Converter

#### **Capacitor Selection**

The TCM680 requires only 4 external capacitors for operation. These can be inexpensive polarized aluminum electrolytic types. For the circuit in Figure 6 the output characteristics are largely determined by the external capacitors. An expression for  $R_{OUT}$  can be derived as shown below:

 $\begin{aligned} \mathsf{R}^+_{\mathsf{OUT}} &= 4(\mathsf{R}_{\mathsf{SW1}} + \mathsf{R}_{\mathsf{SW2}} + \mathsf{ESR}_{\mathsf{C1}} + \mathsf{R}_{\mathsf{SW3}} + \mathsf{R}_{\mathsf{SW4}} + \mathsf{ESR}_{\mathsf{C2}}) \\ &+ 4(\mathsf{R}_{\mathsf{SW1}} + \mathsf{R}_{\mathsf{SW2}} + \mathsf{ESR}_{\mathsf{C1}} + \mathsf{R}_{\mathsf{SW3}} + \mathsf{R}_{\mathsf{SW4}} + \mathsf{ESR}_{\mathsf{C2}}) \\ &+ 1/(\mathsf{f}_{\mathsf{PUMP}} \times \mathsf{C1}) + 1/(\mathsf{f}_{\mathsf{PUMP}} \times \mathsf{C2}) + \mathsf{ESR}_{\mathsf{C4}} \end{aligned}$ 

$$\begin{split} R^-_{OUT} &= 4(R_{SW1} + R_{SW2} + ESR_{C1} + R_{SW3} + R_{SW4} + ESR_{C2}) \\ &+ 4(R_{SW1} + R_{SW2} + ESR_{C1} + R_{SW3} + R_{SW4} + ESR_{C2}) \\ &+ 1/(f_{PUMP} \times C1) + 1/(f_{PUMP} \times C2) + ESR_{C3} \end{split}$$

Assuming all switch resistances are approximately equal...

 $R_{OUT}^{+} = 32R_{SW} + 8ESR_{C1} + 8ESR_{C2} + ESR_{C4} + 1/(f_{PUMP} \times C1) + 1/(f_{PUMP} \times C2)$ 

 $R_{OUT}^{-} = 32R_{SW} + 8ESR_{C1} + 8ESR_{C2} + ESR_{C3}$  $+1/(f_{PUMP} \times C1) + 1/(f_{PUMP} \times C2)$ 

 $R_{OUT}$  is typically 140 $\Omega$  at +25°C with  $V_{IN}$  = +5V and C1 and C2 as 4.7 $\mu$ F low ESR capacitors. The fixed term (32R<sub>SW</sub>) is about 130 $\Omega$ . It can be seen easily that increasing or decreasing values of C1 and C2 will affect efficiency by changing R<sub>OUT</sub>. However, be careful about ESR. This term can quickly become dominant with large electrolytic capacitors. Table 1 shows R<sub>OUT</sub> for various values of C1 and C2 (assume 0.5 $\Omega$  ESR). C1 and C4 must be rated at 6VDC or greater while C2 and C3 must be rated at 12VDC or greater.

Output voltage ripple is affected by C3 and C4. Typically the larger the value of C3 and C4 the less the ripple for a given load current. The formula for  $V_{RIPPLE(p-p)}$  is given below:

 $\begin{array}{l} V_{\mathsf{RIPPLE}(p-p)} = \ \{1/[2(f_{\mathsf{PUMP}}/3) \ x \ C4] + 2(\mathsf{ESR}_{C4})\}(I_{\mathsf{OUT}}^+) \\ V_{\mathsf{RIPPLE}(p-p)} = \ \{1/[2(f_{\mathsf{PUMP}}/3) \ x \ C3] + 2(\mathsf{ESR}_{C3})\}(I_{\mathsf{OUT}}^-) \end{array}$ 

For a  $10\mu$ F (0.5 $\Omega$  ESR) capacitor for C3, C4, f<sub>PUMP</sub> = 21kHz and I<sub>OUT</sub> = 10mA the peak-to-peak ripple voltage at the output will be less than 100mV. In most applications (I<sub>OUT</sub> <= 10mA) 10-20 $\mu$ F output capacitors and 1-5 $\mu$ F pump capacitors will suffice. Table 2 shows V<sub>RIPPLE</sub> for different values of C3 and C4 (assume 1 $\Omega$  ESR).

Table	1.	ROUT	vs.	<b>C1</b>	,C2
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<b>C1, C2 (μF)</b>	R <sub>OUT</sub> (Ω)
0.1	1089
0.47	339
1	232
3.3	165
4.7	157
10	146
22	141
100	137

#### Table 2. V<sub>RIPPLE (p-p)</sub> vs. C3, C4 (I<sub>OUT</sub> = 10mA)

C3, C4 (μF)	V <sub>RIPPLE</sub> (mV)		
0.47	1540		
1	734		
3.3	236		
4.7	172		
10	91		
22	52		
100	27		

#### **Paralleling Devices**

Paralleling multiple TCM680s reduces the output resistance of both the positive and negative converters. The effective output resistance is the output resistance of a single device divided by the number of devices. As illustrated in Figure 7, each requires separate pump capacitors  $C_1$  and  $C_2$ , but all can share a single set of reservoir capacitors.

# ±5V Regulated Supplies From A Single 3V Battery

Figure 8 shows a complete ±5V power supply using one 3V battery. The TCM680 provides +6V at  $V_{OUT}^+$ , which is regulated to +5V by the TC55, and –5V by the negative LDO. The input to the TCM680 can vary from 3V to 6V without affecting regulation appreciably. With higher input voltage, more current can be drawn from the outputs of the TCM680. With 5V at  $V_{IN}$ , 10mA can be drawn from both regulated outputs simultaneously. Assuming 150 $\Omega$  source resistance for both converters, with ( $I_L^+$  +  $I_L$ ) = 20mA, the positive charge pump will droop 3V, providing +7V for the negative charge pump.

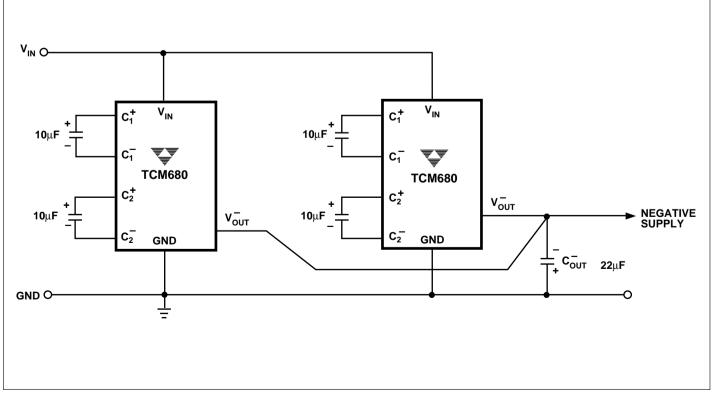


Figure 7. Paralleling TCM680 for Lower Output Source Resistance

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# **TCM680**

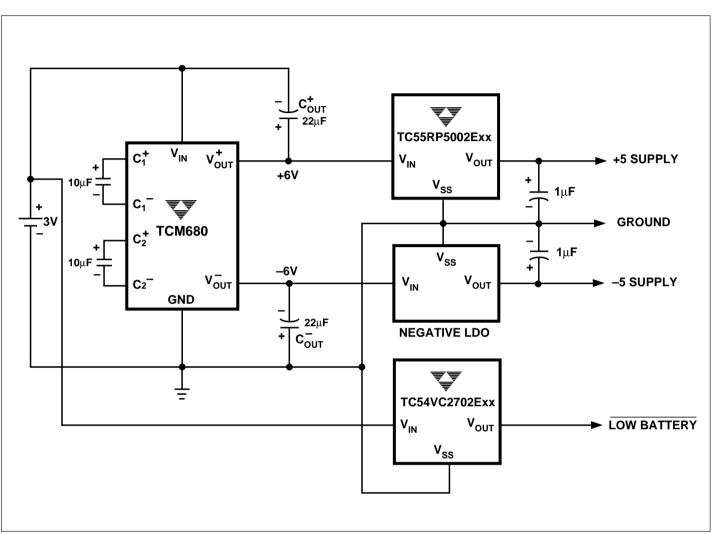
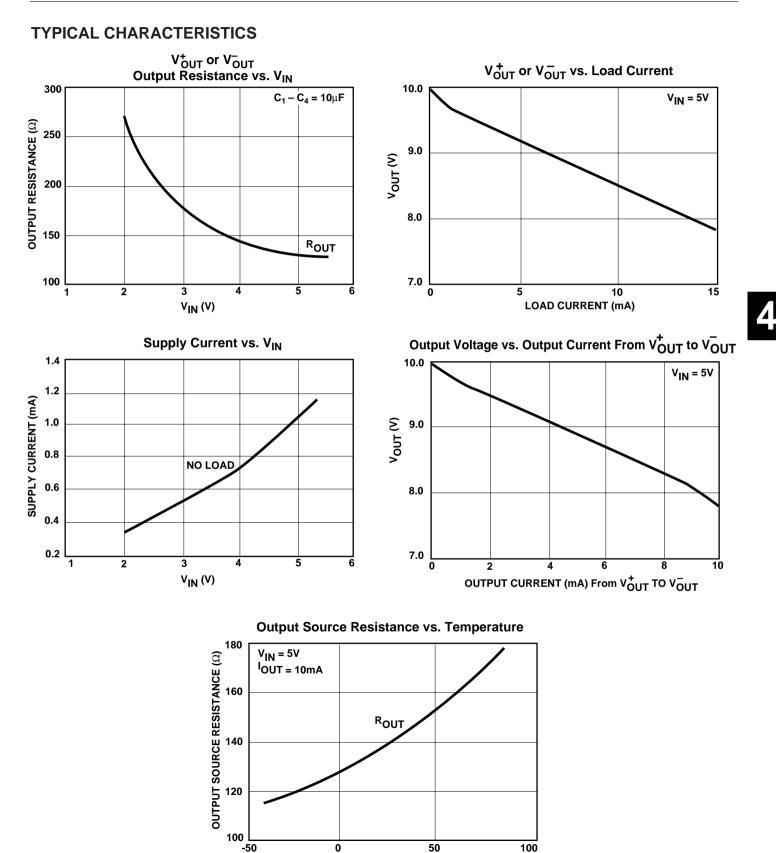


Figure 8. Split Supply Derived from 3V Battery



# +5V TO $\pm$ 10V VOLTAGE CONVERTER



TEMPERATURE (°C)